### **Features**

- ♦ High radiant intensity
- Peak wavelength=  $\lambda_P$ =940nm
- ♦ View angle 30°
- High reliability
- ◆ 2.54mm Lead spacing
- ◆ Low forward voltage
- Pb free
- ◆ The product itself will remain within RoHS compliant version.

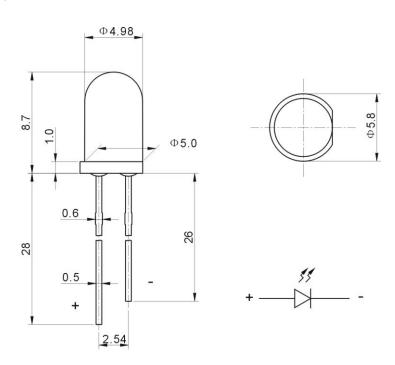
## **Descriptions**

- ♦ Infrared Emitting Diode (OS-5038F) is a high intensity diode, molded in a water clear plastic package.
- ◆ The device is spectrally matched with phototransistor, photodiode and infrared receiver module.

## **Applications**

- ◆ Free air transmission system ◆ Optoelectronic switch ◆ Floppy disk drive
- ◆ Infrared applied system ◆ Smoke detector

## **Package Dimension:**



NOTE:TOLERANCE±0.5mm

Part NO.	Material	Lens Color
OS-5038F	AlGaAs	Water Clear

#### **Notes:**

- 1. All dimensions are in millimeters.
- 2. Tolerances unless dimensions ±0.25mm.

# Absolute Maximum Ratings at Ta=25℃

Parameter	Symbol	Rating	Unit
Continuous Forward Current	$I_{\mathrm{F}}$	100	mA
Power Dissipation at (or below) 25°C Free Air Temperature	Pd	150	mW
Transient PeakCurrent (Pulse width=100 μ s, Duty cycle=1%)	$I_{\mathrm{FP}}$	1000	mA
Reverse Voltage	$V_R$	5	V
Operating Temperature	Topr	-40~+85	${\mathbb C}$
Storage Temperature*	Tstg	-40~+85	${\mathbb C}$
Soldering Temperature	Tsol	260	c

<sup>\* 4</sup>mm from mold body less than 5 seconds

# **Electrical Optical Characteristics:**

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Condition
Forward Voltage	$\mathbf{V_F}$		1.35	1.50	V	I <sub>F</sub> =50mA
Radiant Intensity	Ie	60	76		mW/sr	I <sub>F</sub> =50mA
Peak Wavelength	λp		940		nm	I <sub>F</sub> =50mA
Reverse Current	$I_R$			10	μΑ	$V_R=5V$
Viewing Angle	θ		30		deg	I <sub>F</sub> =50mA

